ZXTP4001Z

60V PNP LED DRIVING TRANSISTOR IN SOT89

Features

- BV_{CEO} > - 60V
- Max continuous current $I_{C\ (cont)}$ = -1A
- h_{FE} > 100 @ I_C = -150mA, V_{CE} = -150mV
- **Totally Lead-Free & Fully RoHS compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

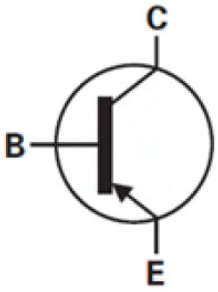
- Case: SOT89
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)

Applications

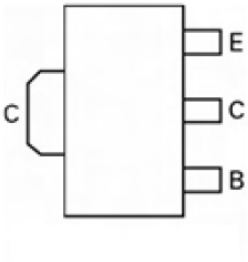
- LED TV backlight

SOT89

Top View



Device symbol



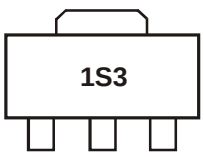
Top View
Pin Out

Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN4001ZTA	1S3	7	12	1000 units

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



1S3 = Product type Marking Code

Maximum Ratings @T_A = 25°C unless otherwise specified

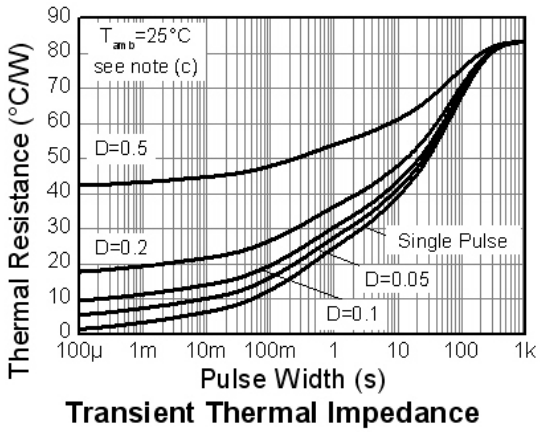
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-60	V
Collector-Emitter Voltage	V_{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	I_C	-1	A
Peak Pulse Current (Note 4)	I_{CM}	-3	A
Base Current	I_B	-500	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

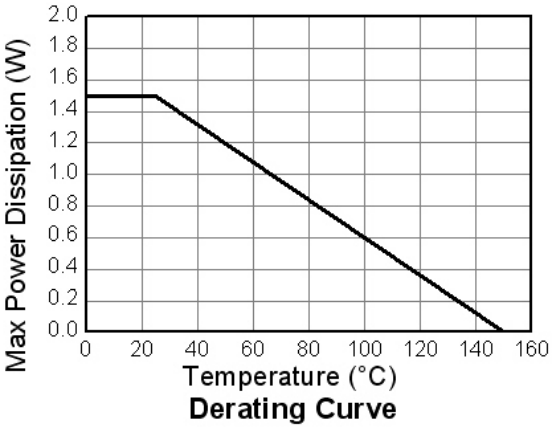
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	83	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{\theta JL}$	22.44	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes: 4. Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤ 2%.
5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions
6. Thermal resistance from junction to solder-point (at the end of the collector lead).

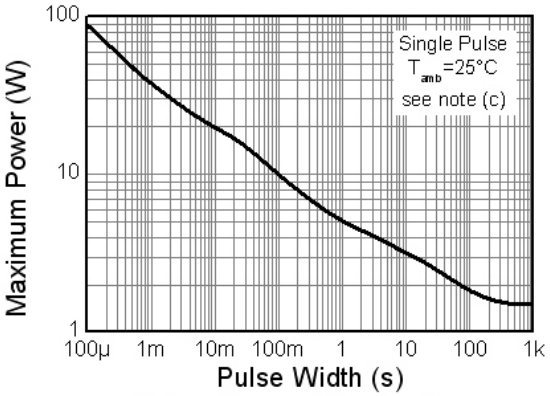
Thermal Characteristics and Derating information



Transient Thermal Impedance



Derating Curve



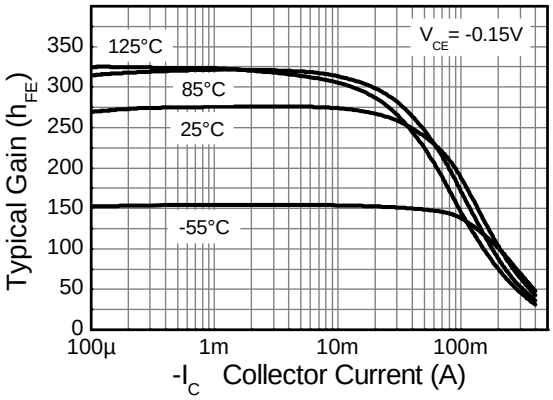
Pulse Power Dissipation

Electrical Characteristics @T_A = 25°C unless otherwise specified

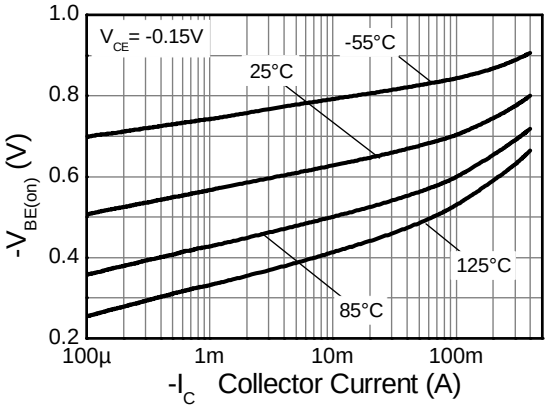
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-60	-	-	V	I_C = -100µA
Collector-Emitter Breakdown Voltage (Note 7)	BV_{CEO}	-60	-	-	V	I_C = -10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.3	-	V	I_E = -100µA
Collector Cut-off Current	I_{CBO}	-	-	-50	nA	V_{CB} = -60V
Emitter Cut-off Current	I_{EBO}	-	-	-50	nA	V_{EB} = -7V
Static Forward Current Transfer Ratio (Note 7)	h_{FE}	60 100	- -	- -	- -	I_C = -85mA, V_{CE} = -0.1V I_C = -150mA, V_{CE} = -0.15V
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	-	-0.72	-0.95	V	I_C = -150mA, V_{CE} = -0.15V
Delay Time	$t_{(d)}$	-	300	-	ns	V_{CC} = -48V, I_C = -150mA, $-I_{B2}$ = 1.5mA, $V_{CE(ON)}$ = -0.15V
Rise Time	$t_{(r)}$	-	420	-	ns	
Storage Time	$t_{(s)}$	-	352	-	ns	
Fall Time	$t_{(f)}$	-	281	-	ns	
Storage Time	$t_{(s)}$	-	48	-	ns	V_{CC} = -48V, I_C = -150mA, $-I_{B2}$ = -1.5mA $V_{CE(ON)}$ = - 4V
Fall Time	$t_{(f)}$	-	245	-	ns	

Notes: 7. Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤ 2%

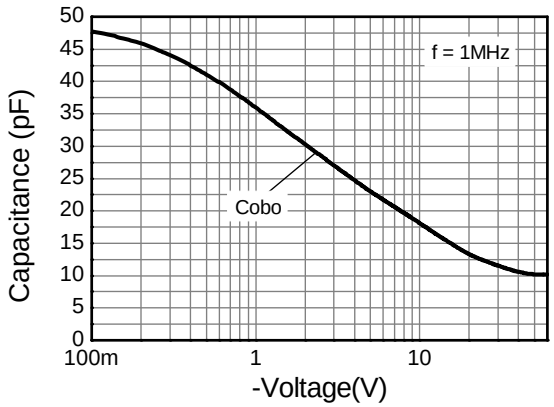
Electrical Characteristics @T_A = 25°C unless otherwise specified



h_{FE} v I_C

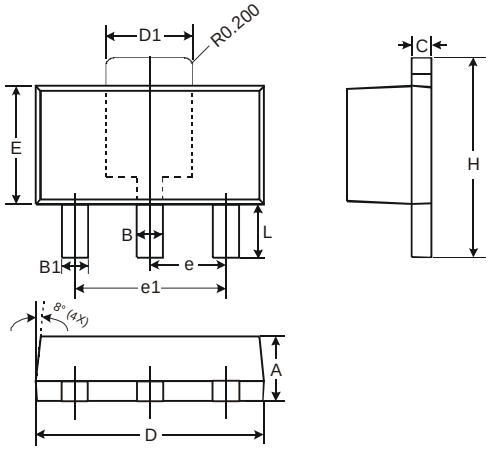


$V_{BE(on)}$ v I_C



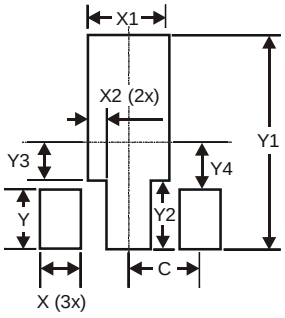
Capacitance v Voltage

Package Outline Dimensions



SOT89		
Dim	**Min**	**Max**
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.43
D	4.40	4.60
D1	1.52	1.83
E	2.29	2.60
e	1.50 Typ	
e1	3.00 Typ	
H	3.94	4.25
L	0.89	1.20
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500

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